

	Type	L #	Hits	Search Text	DBs
1	BRS	L1	1857	vertical adj transistor	USPAT
2	BRS	L2	982	1 and memory	USPAT
3	BRS	L3	5	second adj planar adj transistor	USPAT
4	BRS	L4	4	1 and (multi adj2 junction)	USPAT
5	BRS	L5	4	("5952692"   "6475857"   "6528896"   "6635921").PN.	US-PGPUB; USPAT; USOCR
6	BRS	L6	0	("7042107").URPN.	USPAT
7	IS&R	L7	1	("5604357").PN.	USPAT
8	IS&R	L8	1	("6635921").PN.	USPAT
9	IS&R	L9	1	("6707089").PN.	USPAT
10	BRS	L10	2	("5952692"   "6072718").PN.	US-PGPUB; USPAT; USOCR
11	BRS	L11	0	("6707089").URPN.	USPAT

	Type	L #	Hits	Search Text	DBs
12	BRS	L12	70	("20010013621"   "20030043637"   "20030207032"   "20030207540"   "20050023602"   "20050023603"   "20050026349"   "4295150"   "4412902"   "4688078"   "4757360"   "4780424"   "4939559"   "5071782"   "5073519"   "5350738"   "5399516"   "5418389"   "5474947"   "5488612"   "5498558"   "5508544"   "5600592"   "5618575"   "5677867"   "5801401"   "5852306"   "5880991"   "5923056"   "5936274"   "5952692"   "5959465"   "5981350"   "5986932"   "5991225"   "6009011"   "6025228"   "6025627"   "6031263"   "6069380"   "6069816"   "6124729"   "6134175"   "6141238"   "6141248"   "6143636"   "6163049"   "6169306"   "6208164"   "6210999"   "6229175"   "6238976"   "6246606"   "6249020"   "6249460"   "6307775"   "6317364"   "6341084"   "6351411"   "6377070"   "6424001"   "6461931"   "6475857"   "6514842"   "6541280"   "6574143"   "6586797"   "6730575"   "6754108"   "6778441") .PN.	US-PGPUB; USPAT; USOCR
13	IS&R	L13	5	(("6635921") or ("6211531") or ("5604357") or ("6211531") or ("5952692") or ("6169308")) .PN.	USPAT

<b>14</b>	BRS	L14	12	("4692997"   "5021839"   "5055887"   "5093699"   "5216262"   "5430011"   "5432362"   "5606177"   "5608231"   "5629231"   "5714766"   "5962864").PN.	US-PGPUB; USPAT; USOCR
<b>15</b>	BRS	L15	16	("6211531").URPN.	USPAT

	Type	L #	Hits	Search Text	DBs
16	BRS	L16	16	("6211531").URPN.	USPAT
17	BRS	L17	1	("5319229").PN.	US-PGPUB; USPAT; USOCR
18	BRS	L18	36	("5604357").URPN.	USPAT
19	BRS	L19	8	multi adj tunnel adj junction	USPAT

	Type	L #	Hits	Search Text	DBs
1	BRS	L1	2007	vertical adj transistor	US-PGPUB; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB
2	BRS	L2	1036	1 and memory	US-PGPUB; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB
3	BRS	L3	7	second adj planar adj transistor	US-PGPUB; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB
4	IS&R	L4	1	("7042107").PN.	USPAT
5	BRS	L5	0	("2005/0029559").URPN.	USPAT
6	BRS	L6	9	multi adj tunnel adj junction	US-PGPUB; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB
7	BRS	L7	561	multi adj2 junction	US-PGPUB; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB
8	BRS	L8	3	1 and 7	US-PGPUB; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB